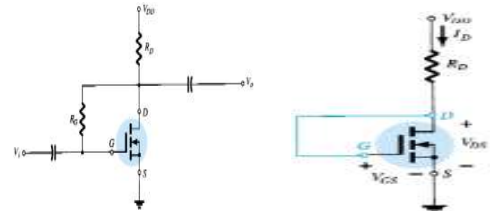


MOSFET.....

Feedback Biasing of n-Channel e-MOSFET

$$I_G = 0$$



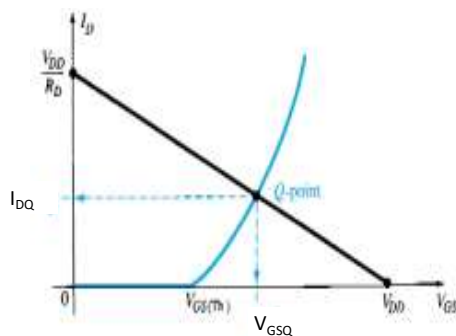
Equations: $V_{DS} = V_{GS}$ $V_{GS} = V_{DD} - I_D R_D$

From the above equations, we get

$$V_{GS} = V_{DD} \Big|_{I_D=0}$$

$$I_D = \frac{V_{DD}}{R_D} \Big|_{V_{GS}=0}$$

Feedback Biasing of n-Channel e-MOSFET



3

Example:

Determine I_{DQ} and V_{DSQ} for the enhancement-type MOSFET of the following ($I_{Don} = 6\text{mA}$, $V_{GS(on)} = 8\text{V}$ and $V_{Gth} = 3\text{V}$).

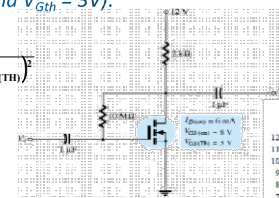
Solution:

We know,
$$k = \frac{I_{D(on)}}{(V_{GS(on)} - V_{GS(th)})^2}$$

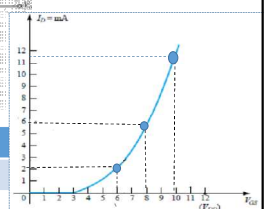
$$= \frac{6\text{mA}}{(8-3)^2}$$

$$= 0.24 \times 10^{-3}$$

$$I_D = k(V_{GS} - V_T)^2$$



V_{GS}	3	6	8	10
I_D	0	2.16mA	6	11.76mA



For the network bias line:

$$V_{GS} = V_{DD} - I_D R_D$$

For $I_D = 0$, $V_{GS} = V_{DD} = 12 \text{ V}$,

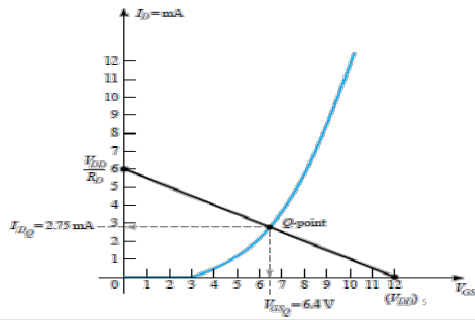
and for $V_{GS} = 0$

$$I_D = V_{DD} / R_D = 12 \text{ V} / 2 \text{ k} = 6 \text{ mA}$$

From the graph

$$V_{GSQ} = 6.4 \text{ V}$$

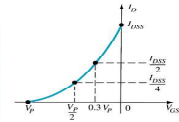
$$I_{DQ} = 2.75 \text{ mA}$$



JFET

$$I_G = 0 \text{ A}, I_D = I_S$$

$$I_D = I_{DSS} \left(1 - \frac{V_{GS}}{V_P}\right)^2$$

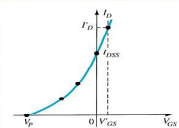


Summary Table

Depletion-MOSFET

$$I_G = 0 \text{ A}, I_D = I_S$$

$$I_D = I_{DSS} \left(1 - \frac{V_{GS}}{V_P}\right)^2$$



Enhancement-MOSFET

$$I_G = 0 \text{ A}, I_D = I_S$$

$$I_D = k \left(\frac{W}{L} \right) (V_{GS} - V_{GS(th)})^2$$

$$k = \frac{\mu_n C_{ox}}{2} \left(\frac{W}{L} \right)$$

